

MSKSEMI 美森科

SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED

MSADP7118AUJZ-x.x

Product specification

GENERAL DESCRIPTION

The MSADP7118AUJZ-x.x series are a group of low-dropout (LDO)voltage regulators offering the benefits of wide input voltage range, low dropout voltage, low power consumption, and miniaturized packaging.

Quiescent current of only 1.5 μ A makes these devices ideal for powering the battery-powered, always-on systems that require very little idle-state power dissipation to a longer service life.

The MSADP7118AUJZ-x.x series of linear regulators are stable with the ceramic output capacitor over its wide input range from 2V to 24V and the entire range of output load current (0mA to 300mA).

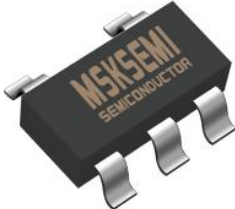
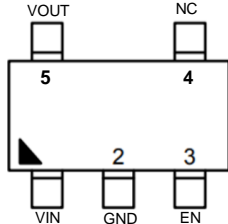
FEATURES

- 1.5 μ A Ground Current at no Load
- $\pm 2\%$ Output Accuracy
- 300mA Output Current
- Wide Operating Input Voltage Range: 2V to 24V
- Dropout Voltage: 0.35V at 100mA / V_{OUT} 5V
- Support Fixed Output Voltage 1.8V, 2.5V, 3.3V, 5V
- Stable with Ceramic or Tantalum Capacitor
- Current Limit Protection
- Over-Temperature Protection
- SOT-23-5 Packages Available

APPLICATIONS

- Portable, Battery Powered Equipment
- Low Power Microcontrollers
- Laptop, Palmtops and PDAs
- Wireless Communication Equipment
- Audio/Video Equipment
- Car Navigation Systems
- Industrial Controls
- Weighting Scales
- Meters
- Home Automation





Reference News

SOT-23-5	PIN CONFIGURATION
	

Description of Functional Pins

Pin No	Pin Name	Pin Function
SOT-23-5		
2	GND	Ground
5	VOUT	Output of the Regulator
1	VIN	Input of Supply Voltage.
4	NC	No Internal Connection.
3	EN	Enable Control Input.

MARKING

MSADP7118AUJZ-1.8	MSADP7118AUJZ-2.5	MSADP7118AUJZ-3.3	MSADP7118AUJZ-5.0
			

ORDER INFORMATION

P/N	Output Voltage	PKG	QTY
MSADP7118AUJZ-1.8	1.8V	SOT-23-5	3000
MSADP7118AUJZ-2.5	2.5V		
MSADP7118AUJZ-3.3	3.3V		
MSADP7118AUJZ-5.0	5.5V		

Typical Application Circuits

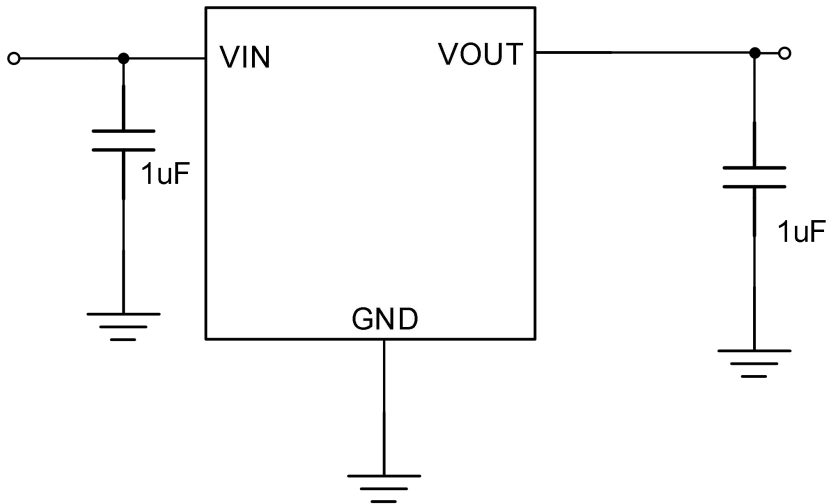
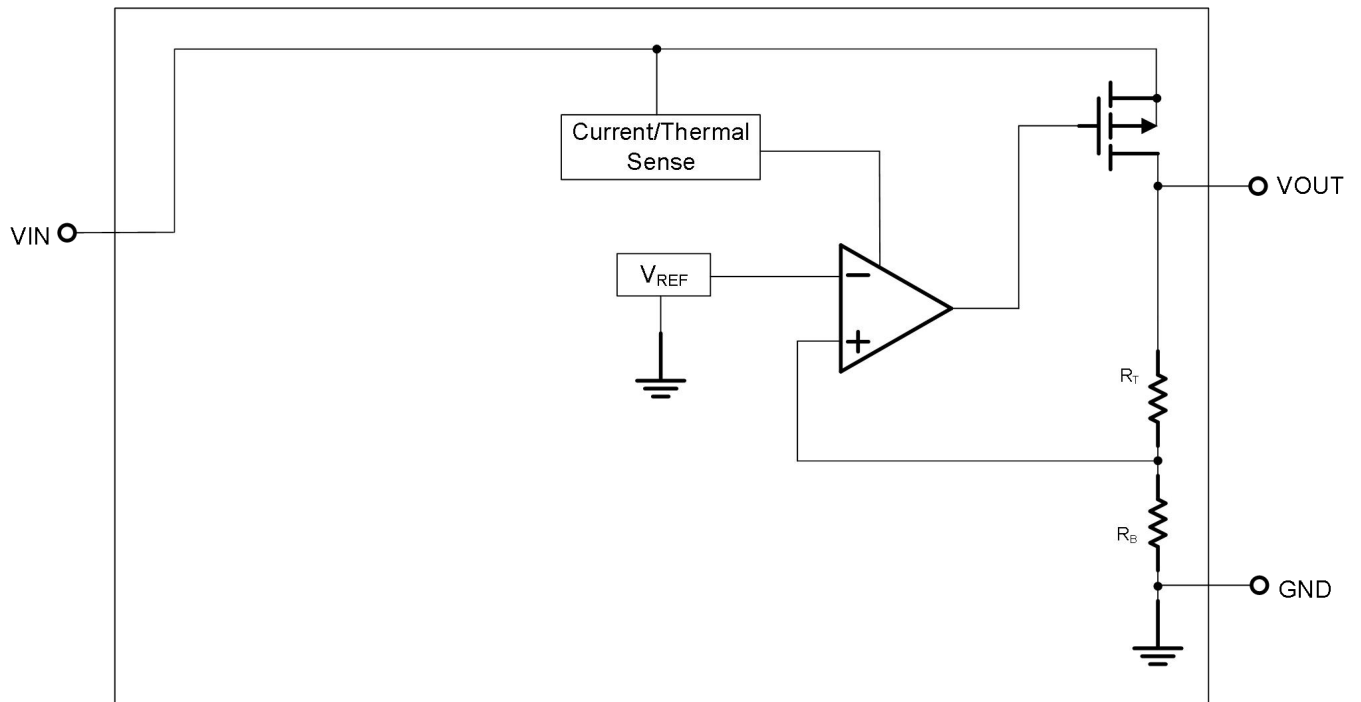


Figure 1: Application circuit of Fixed V_{OUT} LDO

Function Block Diagram



Absolute Maximum Ratings (Note 1)

VIN to GND	-0.3V to 28V
VOUT to GND	
1.8V,2.5V,3.3V,5.0V	-0.3V to 6.0V
VOUT to VIN	-28V to 0.3V
Package Thermal Resistance (Note 2)	
SOT-23-5, θ_{JA}	200 °C /W
Lead Temperature (Soldering, 10 sec.)	260 °C
Junction Temperature	150 °C
Storage Temperature Range	-40 °C to 150 °C
ESD Susceptibility	
HBM	2KV
MM	200V

Recommended Operating Conditions

Input Voltage VIN	2.0V to 24V
Junction Temperature Range	-40 °C to 125 °C
Ambient Temperature Range	-40 °C to 85 °C

Electrical Characteristics

($V_{IN} = 15V$, $V_{EN} = 5V$, $T_A = 25^\circ C$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Supply Voltage	V_{IN}		2	--	24	V
DC Output Voltage Accuracy		$I_{LOAD} = 0.1mA$	-2		2	%
Dropout Voltage ($I_{LOAD} = 100mA$)	V_{DROP}	$V_{OUT} \geq 5V$	--	0.35		V
	$V_{DROP_3.3V}$	$V_{OUT} = 3.3V$		0.42		
	$V_{DROP_1.8V}$	$V_{OUT} = 1.8V$		0.5		
Ground Current ($I_{LOAD} = 0mA$)	I_Q	$V_{OUT} = 5V$		2.2		μA
Line Regulation	$\Delta LINE$	$I_{LOAD} = 1mA$, $5 \leq V_{IN} \leq 30V$	--	0.3		%
Load Regulation	$\Delta LOAD$	$1mA \leq I_{LOAD} \leq 0.2A$		0.1		%
Output Current Limit	I_{LIM}	$V_{OUT} = 0$		300	500	mA
Power Supply Rejection Ratio	PSRR	$V_{OUT} = 5V$, $I_{LOAD} = 1mA$, $V_{IN} = 12V$, $f = 100Hz$		70		dB
Thermal Shutdown Temperature	T_{SD}	$I_{LOAD} = 10mA$	--	160	--	$^\circ C$
Thermal Shutdown Hysteresis	ΔT_{SD}			15		$^\circ C$

Note 1. Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Application Guideline

Input and Output Capacitor Requirements

The external input and output capacitors of MSAD P7118AUJZ-x.x series must be properly selected for stability and performance. Use a 1 μ F or larger input capacitor and place it close to the IC's VIN and GND pins. Any output capacitor meeting the minimum 1m Ω ESR (Equivalent Series Resistance) and effective capacitance between 1 μ F and 22 μ F requirement may be used. Place the output capacitor close to the IC's VOUT and GND pins. Increasing capacitance and decreasing ESR can improve the circuit's PSRR and line transient response.

Current Limit

The MSADP7118AUJZ-x.x series contain the current limiter of output power transistor, which monitors and controls the transistor, limiting the output current to 500mA (typical).

The output can be shorted to ground indefinitely without damaging the part.

Dropout Voltage

The MSADP7118AUJZ-x.x series use a PMOS pass transistor to achieve low dropout. When ($V_{IN} - V_{OUT}$) is less than the dropout voltage (V_{DROP}) the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $R_{DS(ON)}$ of the PMOS pass element. V_{DROP} scales approximately with the output current because the PMOS device behaves as a resistor in dropout condition.

Layout Consideration

By placing input and output capacitors on the same side of the PCB as the LDO, and placing them as close as is practical to the package can achieve the best performance. The ground connections for input and output capacitors must be back to the MSADP7118AUJZ-x.x ground pin using as wide and as short of a copper trace as is practical. Connections using long trace lengths, narrow trace widths, and/or connections through via must be avoided. These add parasitic inductances and resistance that results in worse performance especially during transient conditions.

As any linear regulator, PSRR and transient response are degraded as ($V_{IN} - V_{OUT}$) approaches dropout condition.

OTP (Over Temperature Protection)

The over temperature protection function of MSAD P7118AUJZ-x.x series will turn off the PMOSFET when the junction temperature exceeds 160°C (typ.). Once the junction temperature cools down by approximately 15°C, the regulator will automatically resume operation.

Thermal Application

For continuous operation, do not exceed the absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated as below:

The max PD (Max) = $(125^{\circ}\text{C} - 25^{\circ}\text{C}) / (200^{\circ}\text{C/W}) = 0.5\text{W}$ for SOT-23-3 / SOT-23-5 packages.

The max PD (Max) = $(125^{\circ}\text{C} - 25^{\circ}\text{C}) / (120^{\circ}\text{C/W}) = 0.83\text{W}$ for SOT-89-3 package

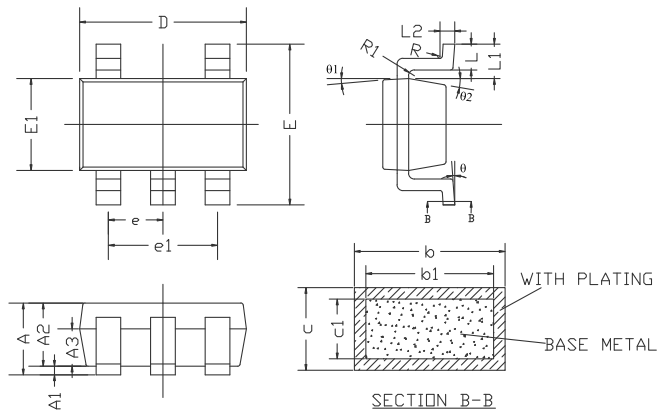
Power dissipation (PD) is equal to the product of the output current and the voltage drop across the output pass element, as shown in the equation below:

$$PD = (V_{IN} - V_{OUT}) \times I_{OUT}$$

Package Outline

Package SOT-23-5

Package dimension (mm):



Devices per reel

Symbol	MIN	NORM	MAX
A	-	-	1.25
A1	0.00	-	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	-	0.50
b1	0.36	0.38	0.45
c	0.14	-	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59 REF		
L2	0.25 BSC		
R	0.05	-	-
R1	0.05	-	0.20
θ	0°	-	8°
$\theta1$	3°	5°	7°
$\theta2$	6°	-	14°

Attention

■ Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.

■ MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specification of any and all MSKSEMI Semiconductor products described or contained herein.

■ Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

■ MSKSEMI Semiconductor strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

■ In the event that any or all MSKSEMI Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

■ No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.

■ Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringement of intellectual property rights or other rights of third parties.

■ Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the MSKSEMI Semiconductor product that you intend to use.